NSN 5961-01-281-7400

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-281-7400 **Inclosure Material:** Metal and ceramic **Overall Length:** 10.55 millimeters **Overall Height:** 1.8 millimeters **Function For Which Designed:** General purpose **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 14.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open and 30.0 collector to base voltage/static/emitter open **Current Rating Per Characteristic:** 50.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 25.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization: No